

# UNISONIC TECHNOLOGIES CO., LTD

# 100N02

## Power MOSFET

TO-251

TO-252

# 100A, 15V N-CHANNEL **POWER TRENCH MOSFET**

#### DESCRIPTION

The UTC 100N02 is an N-channel Power Trench MOSFET, it uses UTC's advanced technology to provide customers with a minimum on-state resistance, low gate charge and high switching speed.

The UTC 100N02 is generally applied in synchronous Rectification or DC to DC convertor.

### **FEATURES**

\*  $R_{DS(ON)} \le 7.5 m\Omega @ V_{GS} = 4.5 V, I_D = 55 A$ 

- $R_{DS(ON)} \le 17m\Omega @ V_{GS}=3.5V, I_D=30A$
- \* Low Gate Charge (Typical 46nC)
- \* High Switching Speed
- \* High Power and Current Handling Capability

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ORDERING INFORMATION							
Ordering Number		Package	Pin Assignment			Decking	
Lead Free	Halogen Free		1	2	3	Packing	
100N02L-TM3-T	100N02G-TM3-T	TO-251	G	D	S	Tube	
100N02L-TN3-R	100N02G-TN3-R	TO-252	G	D	S	Tape Reel	

Note: Pin Assignment: G: Gate D: Drain S: Source

100N02G- <u>TM3-T</u> (1)Packing Type	(1) R: Tape Reel, T: Tube			
(2)Package Type	(2) TN3: TO-252, TM3: TO-251			
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free			

#### MARKING



#### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V <sub>DSS</sub>	15	V	
Gate-Source Voltage		V <sub>GSS</sub>	±8	V	
	Continuous	ID	100	А	
Drain Current	Pulsed	I <sub>DM</sub>	400	А	
Avalanche Energy	Single Pulsed	E <sub>AS</sub>	12	mJ	
Power Dissipation		PD	54	W	
Junction Temperature		TJ	+150	°C	
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### **THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	$\theta_{JA}$	62.5	°C/W	
Junction to Case	θ <sub>JC</sub>	2.3	°C/W	

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

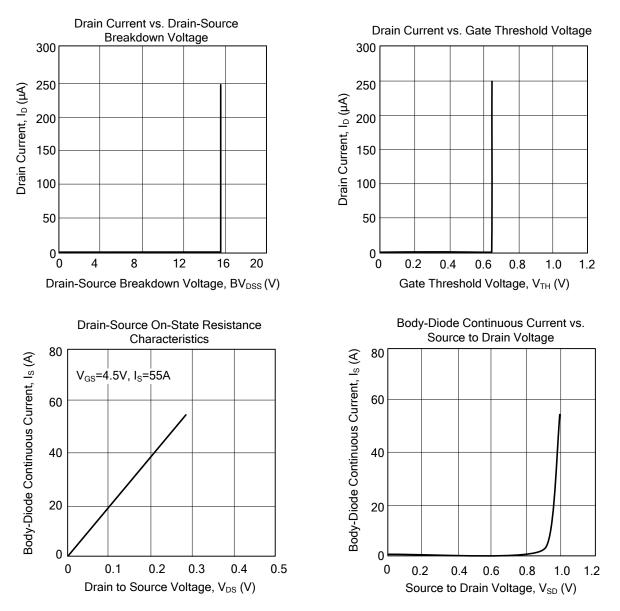
#### **ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0V	15			V	
Drain-Source Leakage Current	I <sub>DSS</sub>	V <sub>DS</sub> =15V			1	μA	
Forward	- I <sub>GSS</sub>	V <sub>GS</sub> =+8V			±100	nA	
Gate-Source Leakage Current Reverse		V <sub>GS</sub> =-8V			±100	nA	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	I <sub>D</sub> =250μA	0.5		1.2	V	
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =55A			7.5	mΩ	
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =3.5V, I <sub>D</sub> =30A			17	mΩ	
DYNAMIC PARAMETERS		•					
Input Capacitance	CISS			3565		рF	
Output Capacitance	Coss	V <sub>GS</sub> =0V, V <sub>DS</sub> =20V, f=1.0MHz		1310		pF	
Reverse Transfer Capacitance	C <sub>RSS</sub>			395		pF	
SWITCHING PARAMETERS							
Total Gate Charge	$Q_{G}$			46	60	nC	
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> =10V, V <sub>DD</sub> =12V, I <sub>D</sub> =0.3A,		6.9		nC	
Gate to Drain Charge	Q <sub>GD</sub>	-I <sub>G</sub> =100μA		9.8		nC	
Turn-ON Delay Time	t <sub>D(ON)</sub>			9		ns	
Rise Time	t <sub>R</sub>	$V_{DD}$ =10V, I <sub>D</sub> =0.16A, R <sub>G</sub> =25 $\Omega$ , $V_{GS}$ =0~10V		106		ns	
Turn-OFF Delay Time	t <sub>D(OFF)</sub>			53		ns	
Fall-Time	t <sub>F</sub>			41		ns	
SOURCE- DRAIN DIODE RATINGS AND	CHARACTER	ISTICS					
Drain-Source Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =55A			1.3	V	
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### **TYPICAL CHARACTERISTICS**



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